## FC694301

## Silicon N-channel MOS FET

For switching circuits

Overview
FC694301 is dual N-channel small signal MOS FET employed small size surface mounting package.

## Features

- High-speed switching
- Low drain-source ON resistance: $\mathrm{R}_{\mathrm{DS}(\text { on })}$ typ. $=3 \Omega\left(\mathrm{~V}_{\mathrm{GS}}=2.5 \mathrm{~V}\right)$
- Small size surface mounting package: SSMini6-F3-B
- Eco-friendly Halogen-free package

Packaging
Embossed type (Thermo-compression sealing): $8000 \mathrm{pcs} /$ reel (standard)
$\square$ Absolute Maximum Ratings $\mathrm{T}_{\mathrm{a}}=25^{\circ} \mathrm{C}$

| Parameter |  | Symbol | Rating | Unit |
| :---: | :--- | :---: | :---: | :---: |
| FET1 | Drain-source surrender voltage | $\mathrm{V}_{\mathrm{DSS}}$ | 30 | V |
|  | Gate-source surrender voltage | $\mathrm{V}_{\mathrm{GSS}}$ | $\pm 12$ | V |
|  | Drain current | $\mathrm{I}_{\mathrm{D}}$ | 100 | mA |
|  | Peak drain current | $\mathrm{I}_{\mathrm{DP}}$ | 200 | mA |
| Overall | Total power dissipation | $\mathrm{P}_{\mathrm{T}}$ | 125 | mW |
|  | Channel temperature | $\mathrm{T}_{\mathrm{ch}}$ | 150 | ${ }^{\circ} \mathrm{C}$ |
|  | Storage temperature | $\mathrm{T}_{\text {stg }}$ | -55 to +150 | ${ }^{\circ} \mathrm{C}$ |

- Package
- Code SSMini6-F3-B
- Pin Name

1: Source (FET1) 4: Source (FET2)
2: Gate (FET1) 5: Gate (FET2)
3: Drain (FET2) 6: Drain (FET1)
Marking Symbol: V4
$\square$ Internal Connection


- Electrical Characteristics $\mathrm{T}_{\mathrm{a}}=25^{\circ} \mathrm{C} \pm 3^{\circ} \mathrm{C}$

| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Drain-source surrender voltage | $\mathrm{V}_{\text {DSS }}$ | $\mathrm{I}_{\mathrm{D}}=1 \mathrm{~mA}, \mathrm{~V}_{\mathrm{GS}}=0$ | 30 |  |  | V |
| Drain-source cutoff current | $\mathrm{I}_{\text {DSS }}$ | $\mathrm{V}_{\mathrm{DS}}=30 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=0$ |  |  | 1.0 | $\mu \mathrm{A}$ |
| Gate-source cutoff current | $\mathrm{I}_{\text {GSS }}$ | $\mathrm{V}_{\mathrm{GS}}= \pm 10 \mathrm{~V}, \mathrm{~V}_{\mathrm{DS}}=0$ |  |  | $\pm 10$ | $\mu \mathrm{A}$ |
| Gate threshold voltage | $\mathrm{V}_{\text {TH }}$ | $\mathrm{I}_{\mathrm{D}}=1.0 \mu \mathrm{~A}, \mathrm{~V}_{\mathrm{DS}}=3.0 \mathrm{~V}$ | 0.5 | 1.0 | 1.5 | V |
| Drain-source ON resistance | $\mathrm{R}_{\mathrm{DS} \text { (on) }}$ | $\mathrm{I}_{\mathrm{D}}=10 \mathrm{~mA}, \mathrm{~V}_{\mathrm{GS}}=2.5 \mathrm{~V}$ |  | 3 | 6 | $\Omega$ |
|  |  | $\mathrm{I}_{\mathrm{D}}=10 \mathrm{~mA}, \mathrm{~V}_{\mathrm{GS}}=4.0 \mathrm{~V}$ |  | 2 | 3 | $\Omega$ |
| Forward transfer admittance | $\left\|\mathrm{Y}_{\mathrm{fs}}\right\|$ | $\mathrm{I}_{\mathrm{D}}=10 \mathrm{~mA}, \mathrm{~V}_{\mathrm{DS}}=3.0 \mathrm{~V}$ | 20 | 55 |  | mS |
| Short-circuit input capacitance (Common source) | $\mathrm{C}_{\text {iss }}$ | $\mathrm{V}_{\mathrm{DS}}=3 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=0, \mathrm{f}=1 \mathrm{MHz}$ |  | 12 |  | pF |
| Short-circuit output capacitance (Common source) | $\mathrm{C}_{\text {oss }}$ |  |  | 7 |  | pF |
| Reverse transfer capacitance (Common source) | $\mathrm{C}_{\text {rss }}$ |  |  | 3 |  | pF |
| Turn-on time * | $\mathrm{t}_{\text {on }}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{DD}}=3 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=0 \mathrm{~V} \text { to } 3 \mathrm{~V}, \\ & \mathrm{R}_{\mathrm{L}}=300 \Omega \end{aligned}$ |  | 100 |  | ns |
| Turn-off time * | $\mathrm{t}_{\text {off }}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{DD}}=3 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=3 \mathrm{~V} \text { to } 0 \mathrm{~V}, \\ & \mathrm{R}_{\mathrm{L}}=300 \Omega \end{aligned}$ |  | 100 |  | ns |

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.
2. *: Test circuit











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